

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of :  
Beom-jun JIN et al. : Attn: Applications Branch  
Serial No. (New) : Attorney Docket No. SEC.872D  
Filed: October 16, 2003 :  
For: SEMICONDUCTOR MEMORY DEVICE HAVING MULTI-LAYERED  
STORAGE NODE CONTACT PLUG AND METHOD FOR FABRICATING  
THE SAME

---

**PRELIMINARY AMENDMENT**

U.S. Patent and Trademark Office  
2011 South Clark Place  
Customer Window, **Mail Stop Patent Application**  
Crystal Plaza Two, Lobby, Room 1B03  
Arlington, VA 22202

Sir:

Preliminary to the examination of the above-identified application, the following  
amendments and remarks are submitted:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on  
page 3 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.